Claims

- A thin film layer structure for use in magnetic recording comprising:

 a pre-seed layer of CrTiAl having an amorphous or nanocrystalline
 structure.
- 2. The thin film structure of claim 1 further comprising a seed layer of RuAl above the layer of CrTiAl, the RuAl having a B2 crystallographic structure.
- 3. The thin film layer structure of claim 1 wherein the layer of CrTiAl is approximately 5 to 20 at.% aluminum.
 - 4. The thin film layer structure of claim 1 wherein the layer of CrTiAl is deposited on a circumferential textured nonmetallic substrate.

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- 5. A magnetic thin film storage medium comprising:
 - a substrate;
 - a layer of CrTiAl deposited on the substrate;
 - a layer of RuAl over the layer of CrTiAl; and
 - at least one underlayer over the layer of RuAl
 - at least one magnetic layer over the underlayer.
- 6. The magnetic thin film storage medium of claim 5 wherein the CrTiAl has from 5 to 20 at.% aluminum.

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- 7. The magnetic thin film storage medium of claim 5 wherein the CrTiAl has approximately from 5 to 20 at.% aluminum with the remainder being approximately equal atomic percentages of chromium and titanium.
- 30 8. The magnetic thin film storage medium of claim 5 wherein the RuAl has a B2 crystallographic structure.

- 9. The magnetic thin film storage medium of claim 5 wherein the CrTiAl is approximately from 10 to 30 nm thick.
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10. A method of fabricating a magnetic thin film storage medium comprising the steps of:

depositing a layer of CrTiAl on a substrate;

depositing a layer of RuAl over the layer of CrTiAl; and

- depositing a plurality of layers over the layer of RuAl, including at least one magnetic layer.
- 11. The method of claim 10 wherein the CrTiAl has from 5 to 20 at.% aluminum.
- 12. The method of claim 10 wherein the CrTiAl has approximately from 5 to 20 at.% aluminum with the remainder being approximately equal atomic percentages of chromium and titanium.
 - 13. The method of claim 10 wherein the RuAl has a B2 crystallographic structure.
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- 14. The method of claim 10 wherein the CrTiAl is from approximately from 10 to 30 nm thick.
- 15. A disk drive comprising:
- a magnetic transducer including a read and a write head;
 - a spindle; and
 - a magnetic thin film disk mounted on the spindle, the magnetic thin film disk including a layer of CrTiAl followed by a layer of RuAl and at least one magnetic layer.

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- 16. The disk drive of claim 15 wherein the CrTiAl has from 5 to 20 at.% aluminum.
- 17. The disk drive of claim 15 wherein the CrTiAl has approximately from 5 to 20 at.% aluminum with the remainder being approximately equal atomic percentages of chromium and titanium.
 - 18. The disk drive of claim 15 wherein the RuAl has a B2 crystallographic structure.

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19. The disk drive of claim 15 wherein the CrTiAl is approximately from 10 to 30 nm thick.